

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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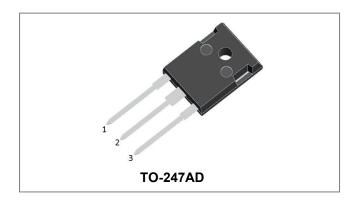








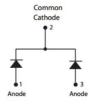
MBR120150WT SCHOTTKY RECTIFIER



Features

- 175 °C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--|--|---|--------------------------------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | - | 150 | V |
| Average Rectified Forward Current | I _{F (AV)} | 50% duty cycle @Tc=150°C, rectangular wave form | 60(Per Leg) 120(Per Device) | Α |
| Peak One Cycle Non-Repetitive Surge Current(Per Leg) | I _{FSM} | 8.3ms, Half Sine pulse | 860 | Α |

Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|-------------------------------|-----------------|---|-------|--------|-------|
| Forward Voltage Drop | V_{F1} | @ 60A, Pulse, T _J = 25℃ | 0.84 | 0.95 | V |
| (Per Leg)* | V _{F2} | @ 60A, Pulse, T _J = 125℃ | 0.75 | 0.80 | V |
| Reverse Current | I _{R1} | @V _R = rated V _R ,T _J = 25℃ | 0.007 | 2 | mA |
| (Per Leg)* | I _{R2} | @V _R = rated V _R ,T _J = 125℃ | 0.4 | 25.0 | mA |
| Junction Capacitance(Per Leg) | Ст | @ $V_R = 5V$, $T_C = 25^{\circ}C$, $f_{SIG} = 1MHz$ | 900 | 1600 | pF |
| Voltage Rate of Change | dv/dt | - | - | 10,000 | V/μs |

 $^{^*\,}$ Pulse width < 300 $\mu s,\,$ duty cycle < 2%

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Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|---|-------------------|--------------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +175 | °C |
| Storage Temperature | T _{stg} | - | -55 to +175 | °C |
| Typical Thermal Resistance Junction to Case | R _{thJC} | DC operation | 0.4 | °C/W |
| Approximate Weight | wt | - | 6.28 | g |
| Case Style | TO-247AD | | | |

Ratings and Characteristics Curves

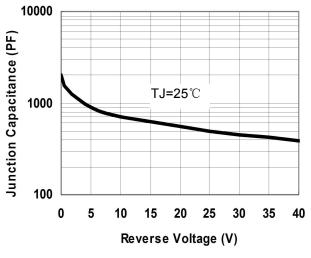


Fig.1-Typical Junction Capacitance

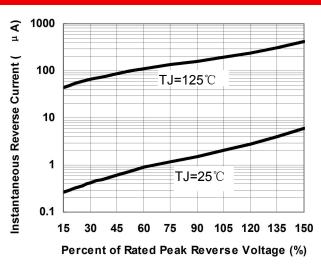


Fig.2-Typical Reverse Characteristics

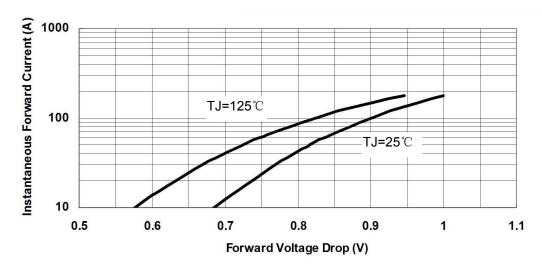


Fig.3-Typical Instantaneous Forward Voltage Characteristics

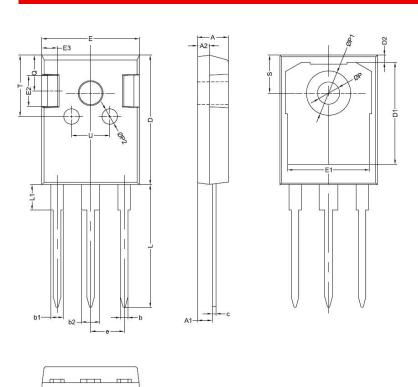
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Mechanical Dimensions TO-247AD



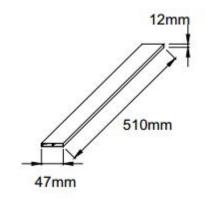
| CVMDOL | Millimeters | | | | |
|-------------|-------------|-------|-------|--|--|
| SYMBOL | MIN. | TYP. | MAX. | | |
| Α | 4.80 | 5.00 | 5.20 | | |
| A1 | 2.20 | 2.41 | 2.61 | | |
| A2 | 1.90 | 2.00 | 2.10 | | |
| b | 1.10 | 1.20 | 1.40 | | |
| b1 | 1.80 | 2.00 | 2.20 | | |
| b2 | 2.80 | 3.00 | 3.20 | | |
| С | 0.50 | 0.60 | 0.75 | | |
| D | 20.30 | 21.00 | 21.20 | | |
| D1 | | 16.55 | | | |
| D2 | | 1.20 | | | |
| E | 15.45 | 15.80 | 16.00 | | |
| E1 | | 13.30 | | | |
| E2 | | 5.00 | | | |
| E3 | | 2.50 | | | |
| е | | 5.44 | | | |
| L | 19.42 | 19.92 | 20.70 | | |
| L1 | | 4.13 | | | |
| Р | 3.50 | 3.60 | 3.70 | | |
| P1 | 7.1 | | 7.40 | | |
| P2 | | 2.50 | | | |
| Q | | 5.80 | | | |
| Q S T | 6.05 | 6.15 | 6.25 | | |
| T | | 10.00 | | | |
| U | | 6.20 | | | |

Ordering Information:

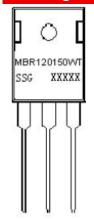
| Device | Package | Shipping | |
|-------------|-------------------|--------------|--|
| MBR120150WT | TO-247AD(Pb-Free) | 25pcs / tube | |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

MBR = Device Type 120 = Forward Current (120A) 150 = Reverse Voltage (150V)

WT = Configuration SSG = SSG YY = Year WW = Week

Cautions: Molding resin

Epoxy resin UL:94V-0

= Lot Number

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